

INFORMATION DISCLOSURE (Use several sheets if necessary)	ATTY DOCKET NO. 18617	APPLICATION NO. 107523418
	APPLICANT(S) Hiroo HONGO	DTU Rec'd PCT/PTO 01 FEB 2005
	FILING DATE	GROUP ART UNIT 2812
	Herewith	Unassigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

U.S. PATENT APPLICATION PUBLICATIONS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
/CL/	JP 2001-20072A	1/23/2001	Japan				
/CL/	JP-2002-115070A	4/19/2002	Japan				
/CL/	JP-2002-115071A	4/19/2002	Japan				
/CL/	JP 2002-105765A	4/10/2002	Japan				
/CL/	JP 2002-180252A	6/26/02	Japan				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/CL/	Jing Kong, et al., Nature, Vol. 395, Page 878 (1998), "Synthesis of Individual Single-Walled Carbon Nanotubes on Patterned Silicon Wafers"
/CL/	Jason H. Hafner, et al., Chemical Physics Letter, Vol. 296, Page 195 (1998), "Catalytic Growth of Single-Wall Carbon Nanotubes from Metal Particles"
/CL/	H. Hongo, et al., Chemical Physics Letters (2002), "Chemical Vapor Deposition of Single-Wall Carbon Nanotubes on Iron-film-coated Sapphire Substrates"
/CL/	S.J. Wind, et al., Applied Physics Letters, Vol. 80, No. 20, (20 May 2002), "Vertical Scaling of Carbon Nanotube Field-Effect Transistors Using Top Gate Electrodes"

EXAMINER /Cheung Lee/	DATE CONSIDERED 10/25/2008
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	ATTY DOCKET NO. 18617	APPLICATION NO. 10523418 Unassigned
	Hiroo HONGO FILING	DT05 Rec'd PCT/PTO 01 FEB 2005 GROUP ART
	Herewith	Unassigned 2812

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						YES	NO
/CL/	JP 2002-146534A	5/22/2002	Japan				
/CL/	JP 2001-176431A	6/29/2001	Japan				
/CL/	JP 2001-48512A	2/20/2001	Japan				
/CL/	JP 11-11917	1/19/1999	Japan				
/CL/	EP 1 129 990 A1	9/5/2001	EPO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/CL/		Seizo Kinoshita, et al., IEICE, Vol. 101, No. 618, pp. 47-52 (2002), "Room Temperature Coulomb Brockade Characteristics of Position Controlled Grown Carbon Nanotube"

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INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)	ATTY DOCKET NO. 18617	APPLICATION NO. 10523418
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FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO
/CL/	8-100328	4/16/1996	Japan				
/CL/	EP 1 061 043 A1	12/20/2000	EPO				

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

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